



**THE DATASHEET OF  
SDUR60Q60W**



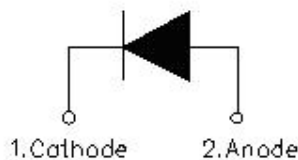
## SDUR60Q60W ULTRAFAST RECTIFIER



### Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Circuit Diagram



### Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification 94V-O
- Terminals finish: 100% Pure Tin
- This is a Pb – free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	$V_{RRM}$	-	600	V
Working Peak Reverse Voltage	$V_{RWM}$			
DC Blocking Voltage	$V_R$			
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_c=70^\circ\text{C}$ , rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3ms, Half Sine pulse	400	A

### Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +175	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-	-55 to +175	$^\circ\text{C}$
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.34	$^\circ\text{C/W}$
Approximate Weight	wt	-	6.28	g
Case Style		TO-247AC		

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25°C	1.9	-	V
	V <sub>F2</sub>	@ 60A, Pulse, T <sub>J</sub> = 25°C	2.3	2.4	V
	V <sub>F3</sub>	@ 30A, Pulse, T <sub>J</sub> = 125°C	1.6	-	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.08	25	µA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125°C	197	500	µA
	I <sub>R3</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 150°C	850	-	µA
Reverse Recovery Time	t <sub>rr1</sub>	I <sub>F</sub> = 500mA, I <sub>R</sub> = 1A, and I <sub>m</sub> = 250mA, T <sub>J</sub> = 25°C	36	40	ns
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 60A, diF/dt = -1000A/µs V <sub>R</sub> = 400V, T <sub>J</sub> = 25°C	44	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		194	-	nC
Reverse Recovery Current	I <sub>RRM</sub>		8.8	-	A
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 60A, diF/dt = -1000A/µs V <sub>R</sub> = 400V, T <sub>J</sub> = 125°C	169	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		1217	-	nC
Reverse Recovery Current	I <sub>RRM</sub>		14.4	-	A
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 30A, diF/dt = -200A/µs V <sub>R</sub> = 400V, T <sub>J</sub> = 25°C	86	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		206	-	nC
Reverse Recovery Current	I <sub>RRM</sub>		4.8	-	A
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 30A, diF/dt = -200A/µs V <sub>R</sub> = 400V, T <sub>J</sub> = 125°C	148	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		562	-	nC
Reverse Recovery Current	I <sub>RRM</sub>		7.6	-	A
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1A, diF/dt = -100A/µs V <sub>R</sub> = 30V, T <sub>J</sub> = 25°C	27	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>		20	-	nC
Reverse Recovery Current	I <sub>RRM</sub>		1.5	-	A

\* Pulse width < 300 µs, duty cycle < 2%

**Ratings and Characteristics Curves**

Figure 1  
Typical Forward Characteristics

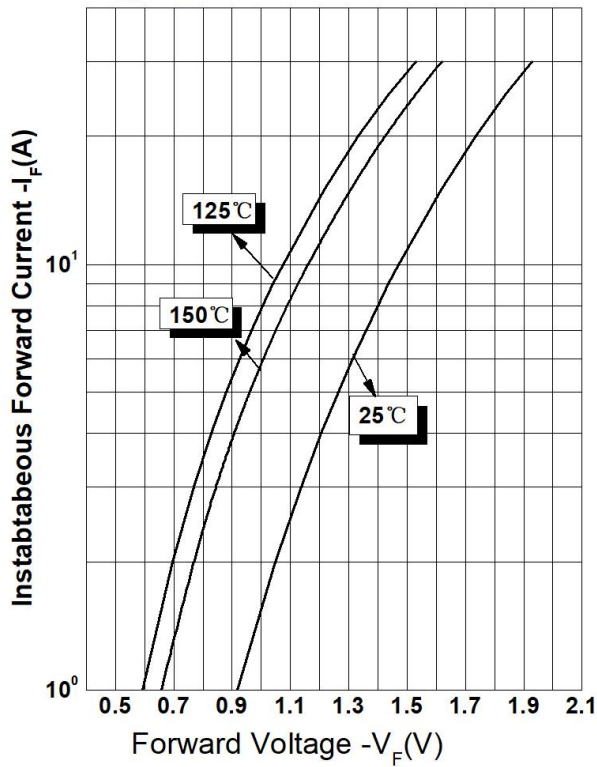


Figure 2  
Typical Reverse Characteristics

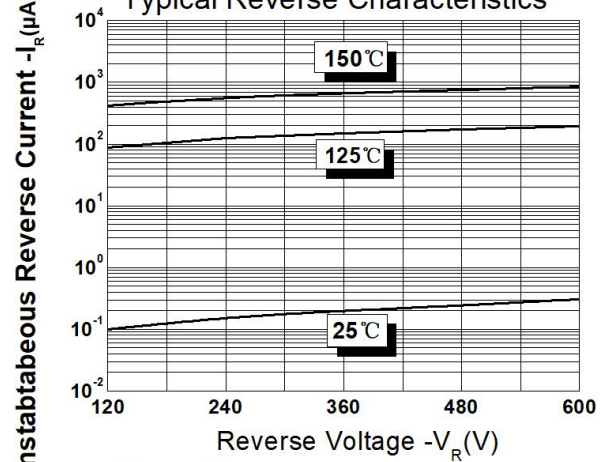
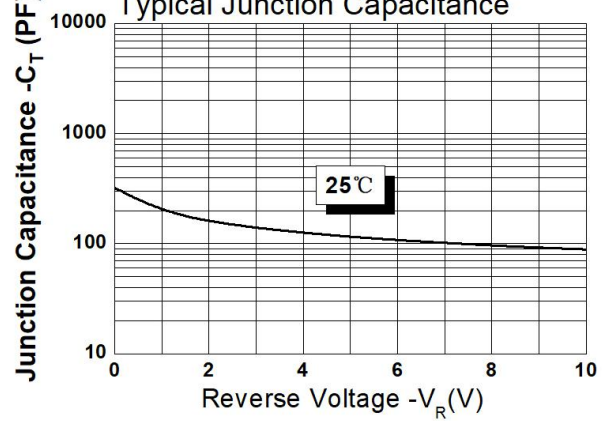
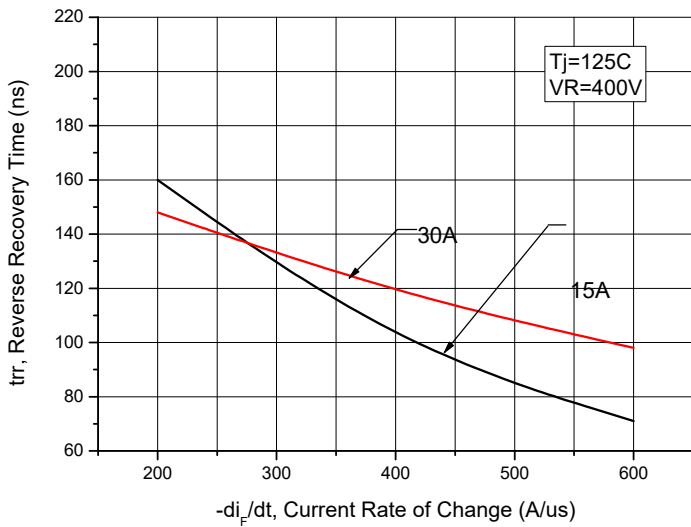
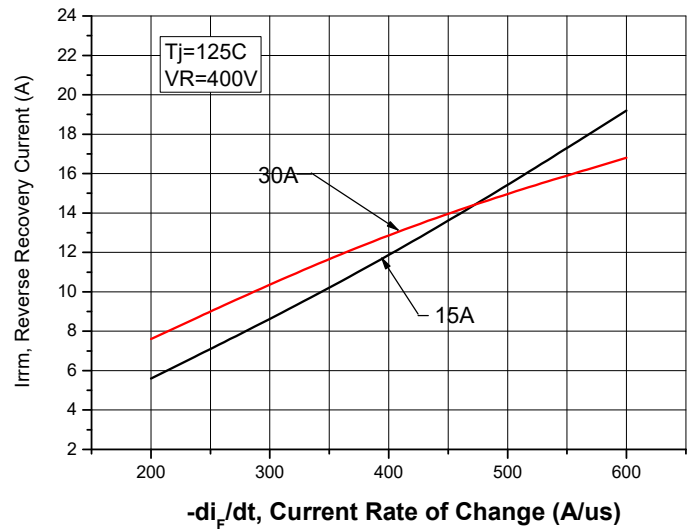


Figure 3  
Typical Junction Capacitance

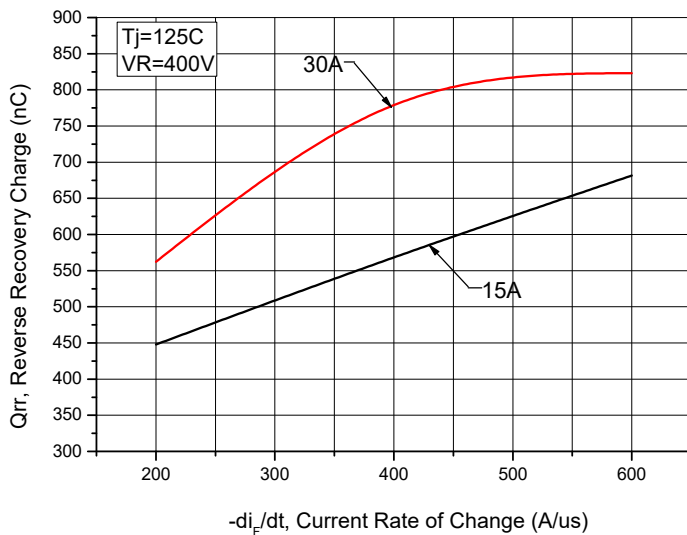




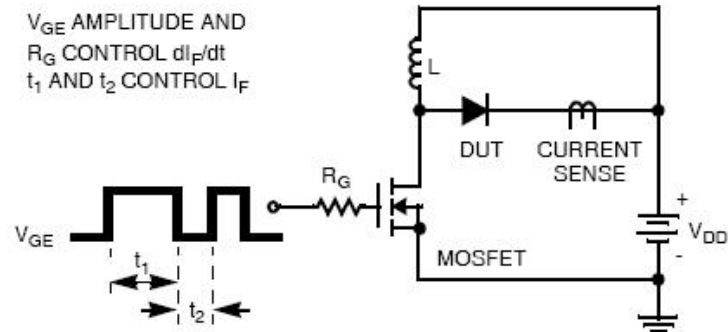
**Figure 4. Reverse Recovery Time vs. Current Rate of Change**



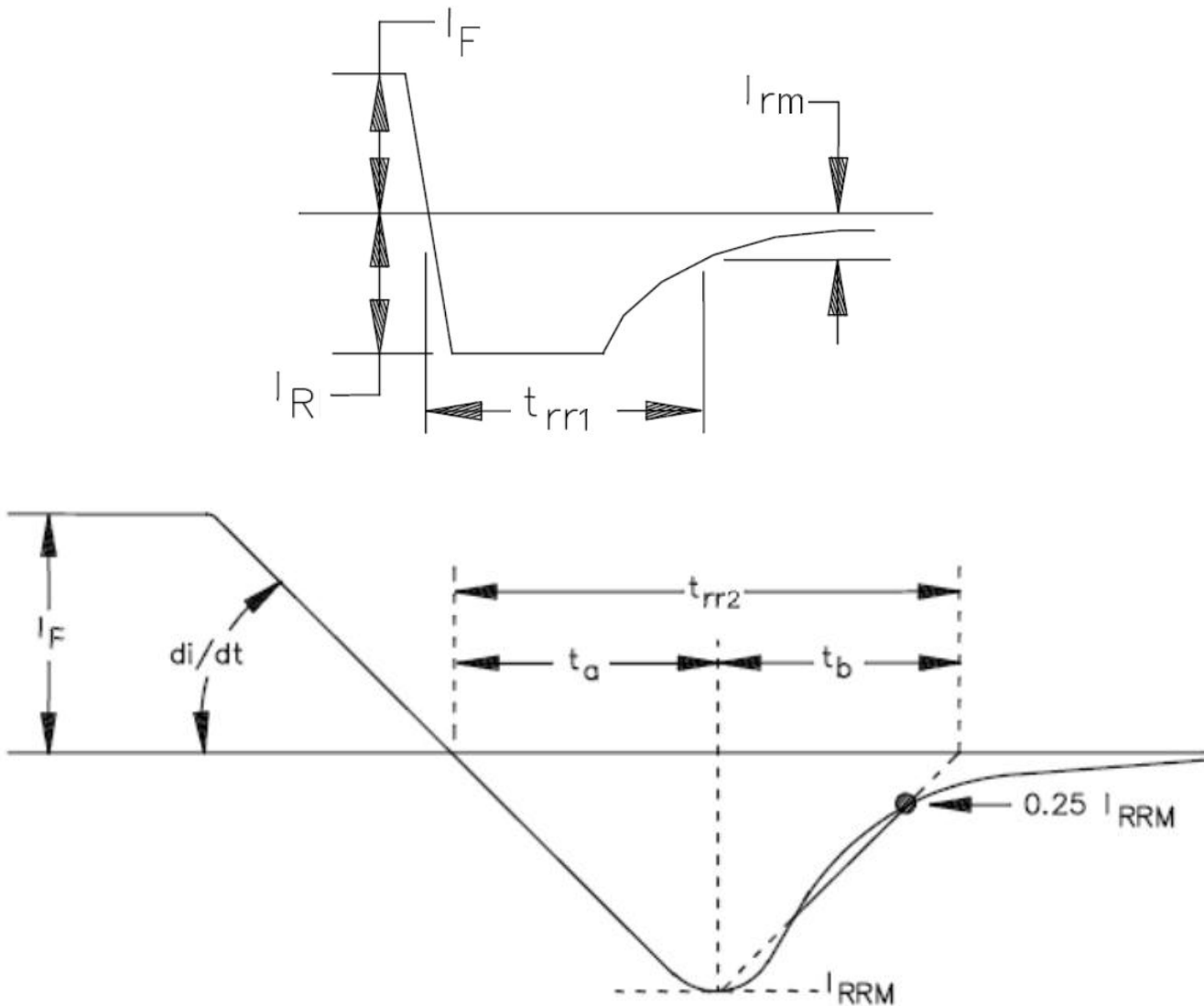
**Figure 5. Reverse Recovery Current vs. Current Rate of Change**



**Figure 6. Reverse Recovery Charge vs. Current Rate of Change**



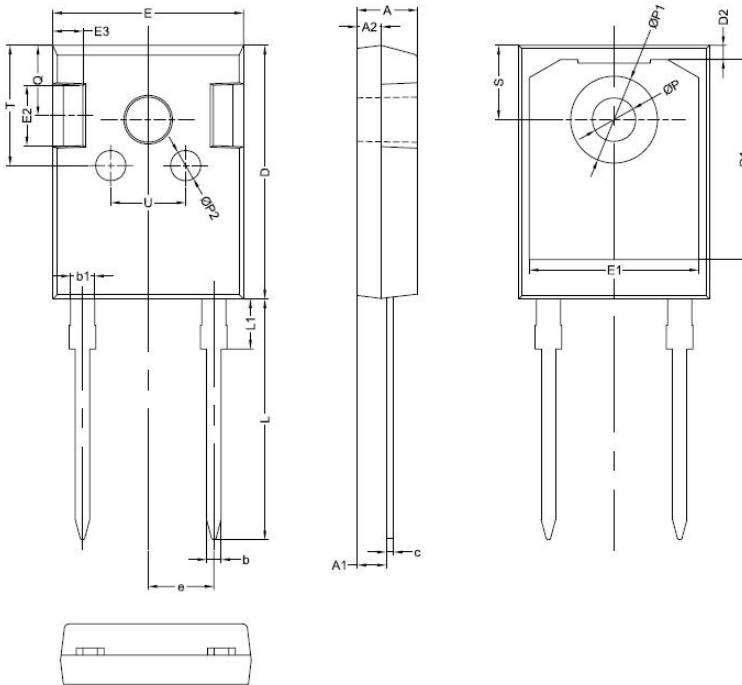
**Figure 7. Diode Test Circuit**



Note: 1.  $t_{rr1}$  MIL-STD-750 Test Method 4031, condition "B".  
2.  $t_{rr2}$  MIL-STD-750 Test Method 4031, condition "D".

**Figure 8 - Reverse Recovery Waveform**

**Mechanical Dimensions TO-247AC**



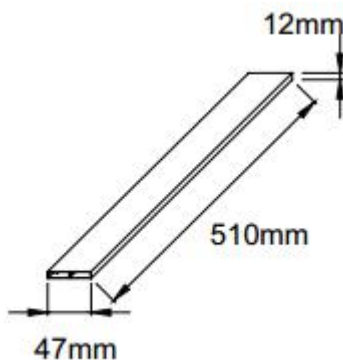
SYMBOL	Millimeters		
	MIN.	TYP.	MAX.
A	4.80	5.00	5.20
A1	2.20	2.41	2.61
A2	1.90	2.00	2.10
b	1.10	1.20	1.35
b1	1.80	2.00	2.20
c	0.50	0.60	0.75
D	20.30	21.00	21.20
D1		16.58	
D2		1.17	
E	15.60	15.80	16.00
E1		14.02	
E2		5.00	
E3		2.50	
e		5.44	
L	19.42	19.92	20.42
L1		4.13	
P	3.50	3.60	3.70
P1	7.1	7.19	7.40
P2		2.50	
Q		5.80	
S	6.05	6.15	6.25
T		10.00	
U		6.20	

**Ordering Information**

Device	Package	Plating	Shipping
SDUR60Q60W	TO-247AC(Pb-Free)	Pure Sn	25pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

**Tube Specification**



**Marking Diagram**



Where XXXXX is YYWWL

- SDUR = Device Type
- 60 = Forward Current (60A)
- Q = Q
- 60 = Reverse Voltage (600V)
- W = Configuration
- SSG = SSG
- YY = Year
- WW = Week
- L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL-94V-0

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